Onsemi

MOSFET – Power, N-Channel

20 V, 14 A, 6.8 mΩ, Single ECH8

ECH8420

Features

- ON-resistance $R_{DS}(on)1 = 5.2 \text{ m}\Omega \text{ (Typ.)}$
- 1.8 V Drive
- Protection Diode in
- This Device is Pb-Free and Halide Free

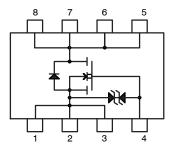


SOT-28FL / ECH8 CASE 318BF

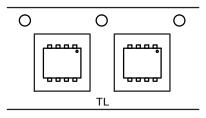
MARKING DIAGRAM



ELECTRICAL CONNECTION



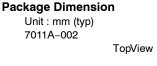
PACKING TYPE: TL



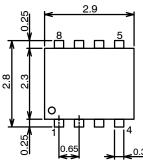
ORDERING INFORMATION

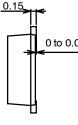
Device	Package	Shipping [†]
ECH8420-TL-H	SOT-28FL / ECH8 (Pb-Free, Halide Free)	3000 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

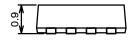


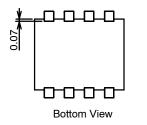
ECH8420-TL-H





ECH8





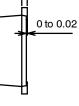




Figure 1. Package Dimensions

Specifications

ABSOLUTE MAXIMUM RATINGS at $T_A = 25^{\circ}C$

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V _{DSS}		20	V
Gate-to-Source Voltage	V _{GSS}		±12	V
Drain Current (DC)	I _D		14	А
Drain Current (Pulse)	I _{DP}	PW \leq 10 μ s, duty cycle \leq 1%	50	А
Allowable Power Dissipation	PD	When mounted on ceramic substrate (900 mm ² \times 0.8 mm)	1.6	W
Channel Temperature	T _{ch}		150	°C
Storage Temperature	T _{stg}		-55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

ELECTRICAL CHARACTERISTICS at T_A = 25°C

Parameter	Symbol	Conditions		Ratings		
			Min	Тур	Max	Unit
Drain-to-Source Breakdown Voltage	V _{(BR)DSS}	I _D = 1 mA, V _{GS} = 0 V	20	-	-	V
Zero-Gate Voltage Drain Current	I _{DSS}	V _{DS} = 20 V, V _{GS} = 0V	-	-	1	μA
Gate-to-Source Leakage Current	I _{GSS}	V_{GS} = ±8 V, V_{DS} = 0 V	-	-	±10	μA
Cutoff Voltage	V _{GS} (off)	V _{DS} = 10 V, I _D = 1 mA	0.4	-	1.3	V
Forward Transfer Admittance	yfs	V _{DS} = 10 V, I _D = 7 A	-	14.5	-	S
Static Drain-to-Source On-State Resistance	R _{DS} (on)1	I _D = 7 A, V _{GS} = 4.5 V	-	5.2	6.8	mΩ
	R _{DS} (on)2	I _D = 4 A, V _{GS} = 2.5 V	-	8	11.5	mΩ
	R _{DS} (on)3	I _D = 2 A, V _{GS} = 1.8 V	-	15	22.5	mΩ
Input Capacitance	Ciss	V _{DS} = 10 V, f = 1 MHz	-	2430	-	pF
Output Capacitance	Coss		-	410	-	pF
Reverse Transfer Capacitance	Crss		-	330	-	pF
Turn–ON Delay Time	t _d (on)	See specified Test Circuit.	-	21	-	ns
Rise Time	t _r		-	88	-	ns
Turn-OFF Delay Time	t _d (off)		-	210	-	ns
Fall Time	t _f		-	115	-	ns
Total Gate Charge	Qg	V _{DS} = 10 V, V _{GS} = 4.5 V,	-	29	-	nC
Gate-to-Source Charge	Qgs	I _D = 14 A	-	4.8	-	nC
Gate-to-Drain "Miller" Charge	Qgd		-	8.7	-	nC
Diode Forward Voltage	V _{SD}	I _S = 14 A, V _{GS} = 0 V	-	0.75	1.2	V

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

ECH8420

Switching Time Test Circuit

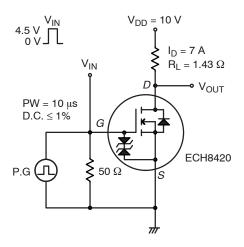
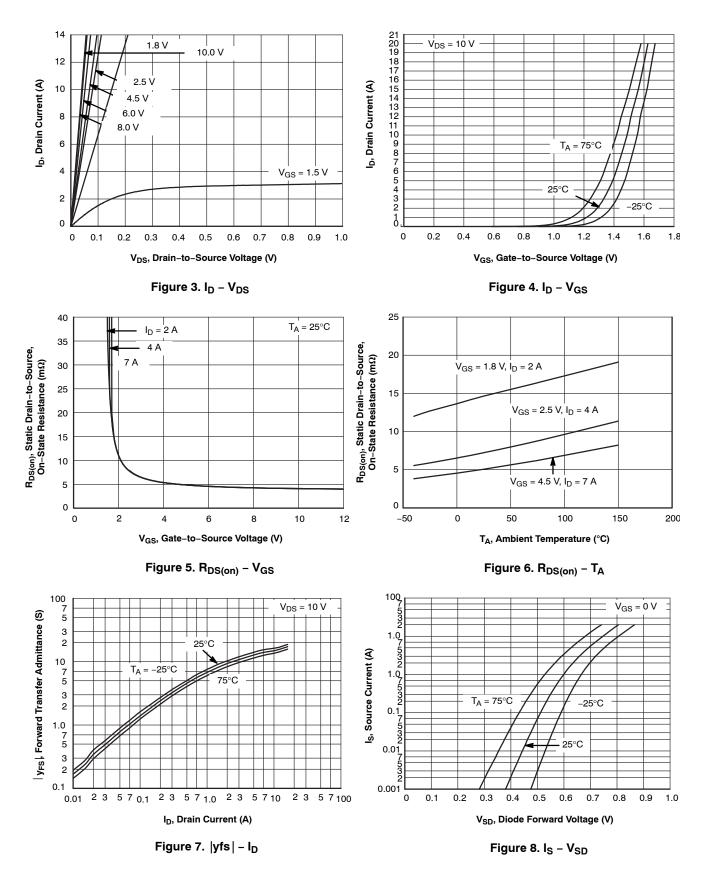


Figure 2. Switching Time Test Circuit

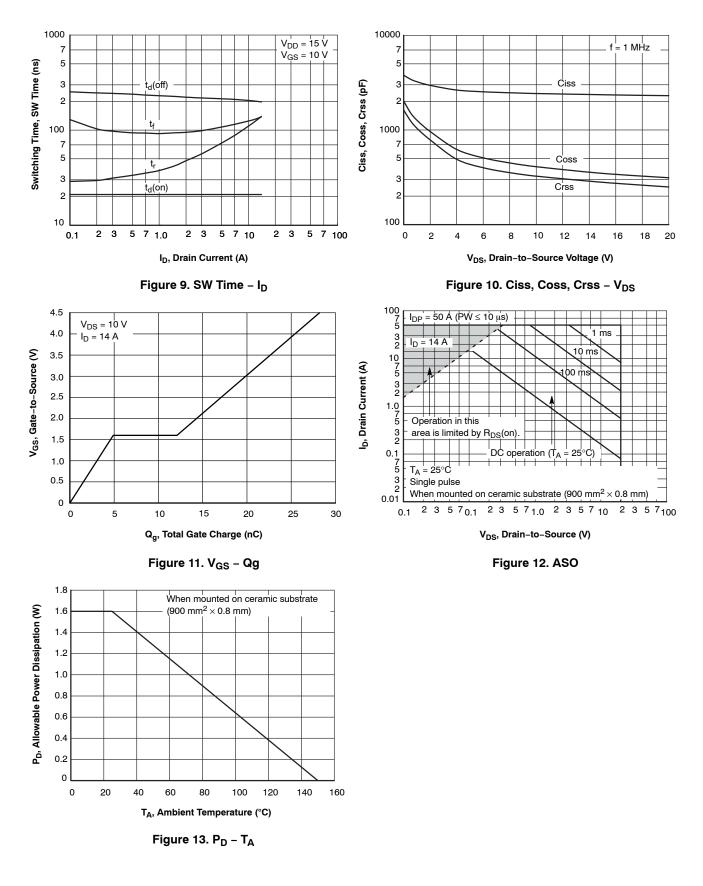
ECH8420

TYPICAL CHARACTERISTICS



ECH8420

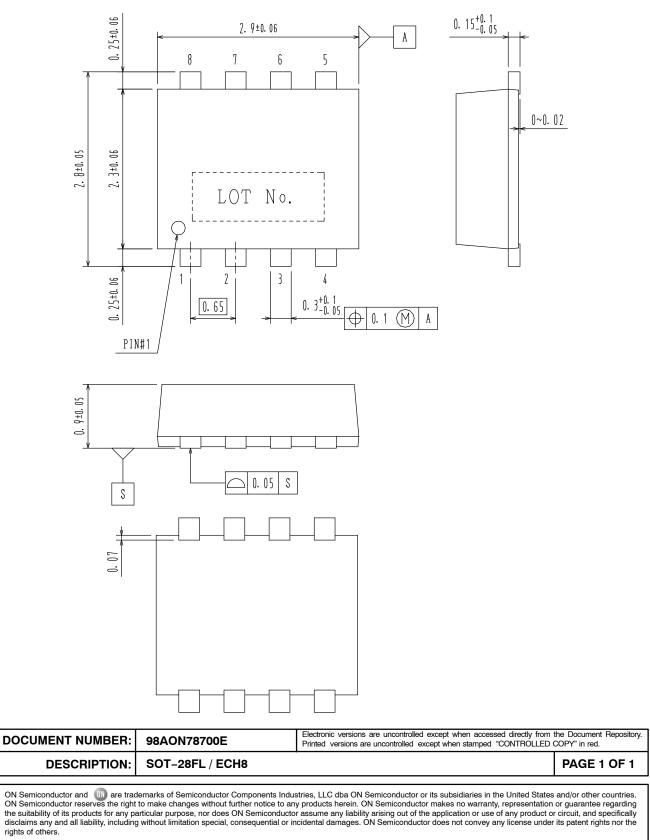
TYPICAL CHARACTERISTICS (continued)





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DATE 31 MAR 2012



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